FAIRCHILD
SEMICONDUCTOR®

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RMWM38001

38 GHz Mixer MMIC

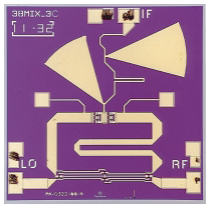
General Description

The RMWM38001 is a 38 GHz Mixer designed for use in point to point and point to multi-point radios, and various communications applications. In conjunction with other Fairchild RF Components amplifiers, multipliers and mixers it forms part of a complete 38 GHz transmit/receive chipset. The RMWM38001 is a GaAs MMIC diode mixer utilizing our 0.25µm power PHEMT process. The MMIC can be used as both an Upconverter and a Downconverter and is sufficiently versatile to serve in a variety of mixer applications.

Features

- 4mil substrate
- Conversion loss 5dB (Upconverter)
- Conversion loss 8dB (Downconverter)
- No DC bias required
- Chip size 1.4mm x 1.4mm

Device



Absolute Ratings

Symbol	Parameter	Ratings	Units
P_{IN}	RF Input Power (from 50Ω source)	+25	dBm
T_C	Operating Baseplate Temperature	-30 to +85	°C
T_{stg}	Storage Temperature Range	-55 to +125	°C

Electrical Characteristics (At 25°C), 50 Ω system, LO = +12 dBm

Parameter	Min	Typ	Max	Units
RF Frequency Range	37		40	GHz
LO Frequency Range		32–35		GHz
IF Frequency Range		4.7–5.3		GHz
LO Drive Power		12	16	dBm
Up Conversion Loss		5		dB
Down Conversion Loss[1]		8	10	dB
Conversion Loss Variation vs Freq.		3		dB

Note:
1: Device 100% RF tested as downconverter only. L0 drive = +12dBm, RF Pin = -10dBm, IF = 5GHz.

Application Information

CAUTION: THIS IS AN ESD SENSITIVE DEVICE.

Chip carrier material should be selected to have GaAs compatible thermal coefficient of expansion and high thermal conductivity such as copper molybdenum or copper tungsten. The chip carrier should be machined, finished flat, plated with gold over nickel and should be capable of withstanding 325°C for 15 minutes.

Die attachment should utilize Gold/Tin (80/20) eutectic alloy solder and should avoid hydrogen environment for PHEMT devices. Note that the backside of the chip is gold plated and is used as RF ground.

These GaAs devices should be handled with care and stored in dry nitrogen environment to prevent contamination of bonding surfaces. These are ESD sensitive devices and should be handled with appropriate precaution including the use of wrist grounding straps. All die attach and wire/ribbon bond equipment must be well grounded to prevent static discharges through the device.

Recommended wire bonding uses 3mils wide and 0.5mil thick gold ribbon with lengths as short as practical allowing for appropriate stress relief. The RF input and output bonds should be typically 0.012" long corresponding to a typical 2mil gap between the chip and the substrate material.

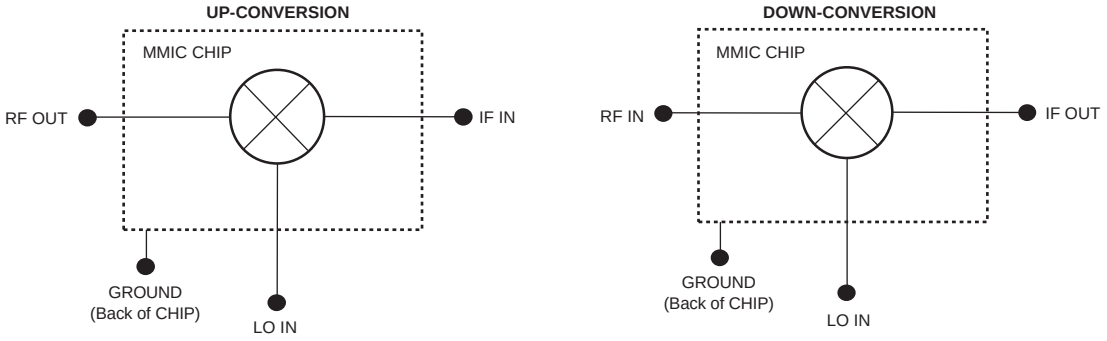


Figure 1. Functional Block Diagram

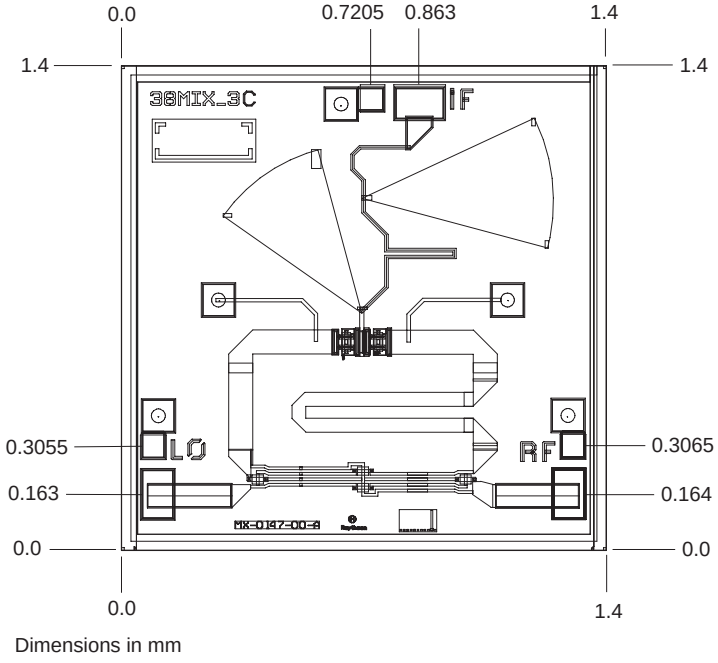


Figure 2. Chip Layout and Bond Pad Locations
(Chip Size is 1.4mm x 1.4mm x 100µm. Back of chip is RF Ground)

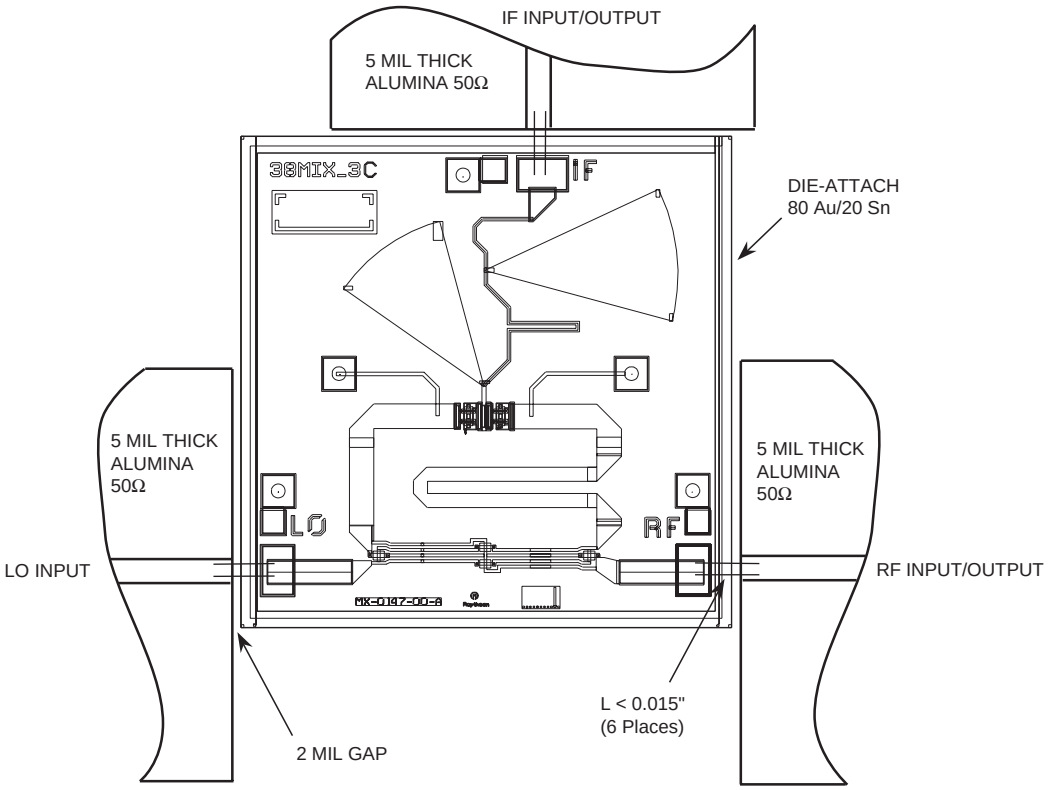


Figure 3. Recommend Assembly Diagram[1]

Note:
1: Use 0.003" by 0.0005" Gold Ribbon for bonding. RF input and output bonds should be less than 0.015" long with stress relief.

Recommended Procedure for Operation

CAUTION: THIS IS AN ESD SENSITIVE DEVICE

The RMWM38001 does not require DC bias. Apply RF input signal at the appropriate frequency band and input driver level.

Typical Characteristics

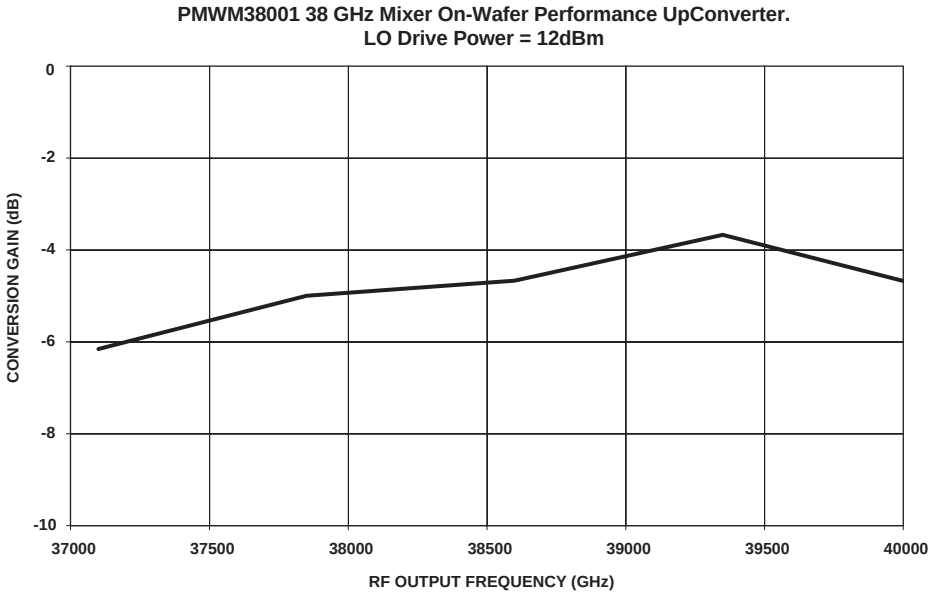


Figure 4.

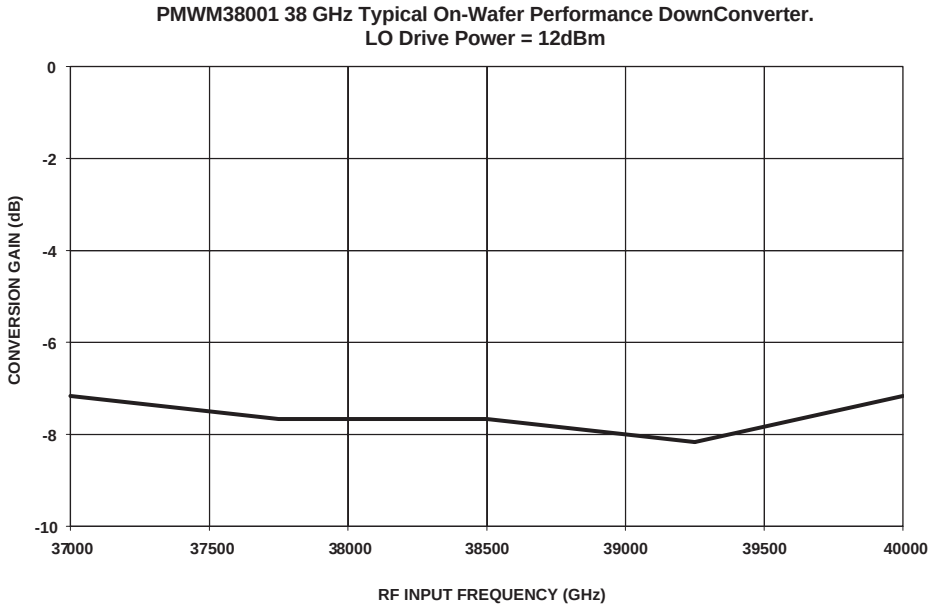


Figure 5.

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DOME™	GTO™	MICROWIRE™	QT Optoelectronics™	TinyLogic®
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EnSigna™	*i-Lo*™	OCX™	RapidConnect™	UHC™
FACT™	ImpliedDisconnect™	OCXPro™	µSerDes™	UltraFET®
FACT Quiet Series™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
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The Power Franchise®		PACMAN™	SPM™	
Programmable Active Droop™		POP™	Stealth™	

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